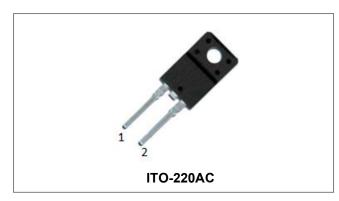


SDURF830

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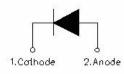
SDURF830 ULTRAFAST RECTIFIER



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Circuit Diagram



Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	300	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=55°C, rectangular wave form	8	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	80	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@8A, Pulse, T _J = 25°C	1.01	1.3	V
	V _{F2}	@8A, Pulse, T _J = 125°C	0.91	1.2	V
Reverse Current*	I _{R1}	$@V_R = rated V_R$, $T_J = 25^{\circ}C$	0.06	10	μA
	I _{R2}	$@V_R = rated V_R$, $T_J = 125^{\circ}C$	6	500	μA
Reverse Recovery Time	trr	I_F =500mA, I_R =1A,and I_m =250mA	39	45	ns

* Pulse width < 300 µs, duty cycle < 2%

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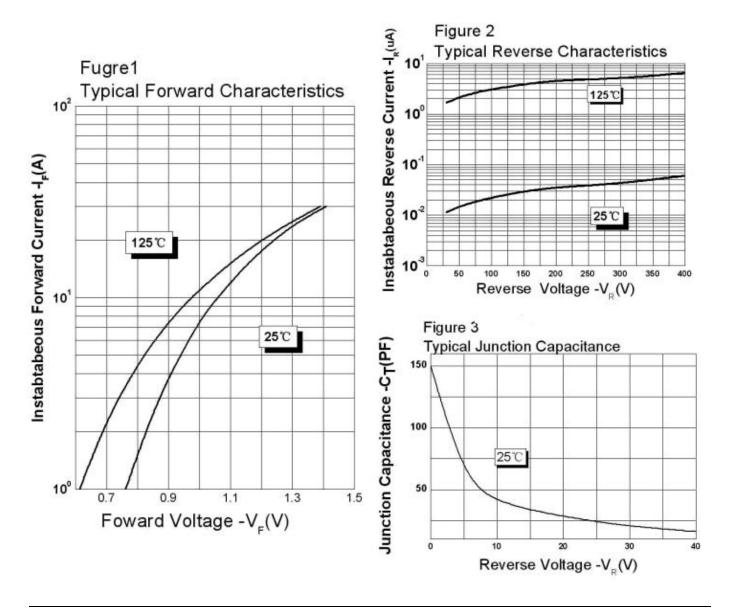


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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	5	°C/W
Approximate Weight	wt	-	1.65	g
Case Style	ITO-220AC			

Ratings and Characteristics Curves





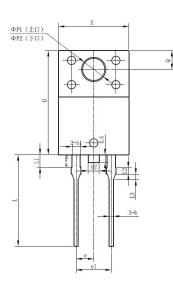
Data Sheet N0404, Rev. B

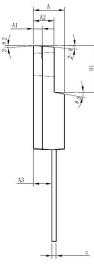
Technical Data

SDURF830

RoHS

Mechanical Dimensions ITO-220AC

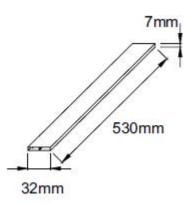




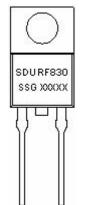
OVMDOL	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
Α	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
С	0.55	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
е	_	2.55	-		
e1	_	5.10	-		
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
L4	_	1.10	1.50		
ΦΡ1(上口)	3.30	3.50	3.70		
ΦΡ2 (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

2-05

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

- SDUR
- = Device Type = Package type = Forward Current (8A) = Reverse Voltage (300V)
- 30

F

8

SSG

YY

WW

L

- = SSG
- = Year
- = Week
- = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping	
SDURF830	ITO-220AC (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

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